

## *DME375A* 375 Watts, 50 Volts, Pulsed Avionics 1025-1150 MHz

<b>GENERAL DESCRIPTION</b> The DME375A is a high power COMMON BASE bipolar transistor. It is designed for pulsed systems in the frequency band 1025-1150 MHz. The device has gold thin-film metallization for proven highest MTTF. The transistor includes input and output prematch for broadband capability. Low thermal resistance package reduces junction temperature, extends life.	CASE OUTLINE 55AW Style 1
ABSOLUTE MAXIMUM RATINGSMaximum Power DissipationDevice Dissipation @25°C2875 W	
Maximum Voltage and CurrentCollector to Base Voltage ( $BV_{ces}$ )55 VEmitter to Base Voltage ( $BV_{ebo}$ )4.0 VCollector Current ( $I_c$ )30 A	
Maximum TemperaturesStorage Temperature-65 to +200 °COperating Junction Temperature+200 °C	

## **ELECTRICAL CHARACTERISTICS @ 25°C**

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
Pout	Power Out	F = 1025 - 1150  MHz	375			W
P <sub>in</sub>	Power Input	Vcc = 50 Volts			85	W
Pg	Power Gain	$PW = 10 \ \mu sec$	6.5			dB
η <sub>c</sub>	Collector Efficiency	DF = 1%		40		%
VSWR <sup>1</sup>	Load Mismatch Tolerance	F = 1090  MHz			<b>—</b> :1	

## FUNCTIONAL CHARACTERISTICS @ 25°C

BV <sub>ebo</sub>	Emitter to Base Breakdown	Ie = $20 \text{ mA}$	4.0		V
BV <sub>ces</sub>	Collector to Emitter Breakdown	Ic = 25 mA	55		V
h <sub>FE</sub>	DC – Current Gain	Vce = 5V, Ic = 300 mA	10		
θjc <sup>2</sup>	Thermal Resistance			0.2	°C/W

NOTE 1: At rated output power and pulse conditions 2. At rated pulse conditions

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**POWER OUTPUT** 

Vcc = 50 V, Pin = 85 W

500

400

300

200

100

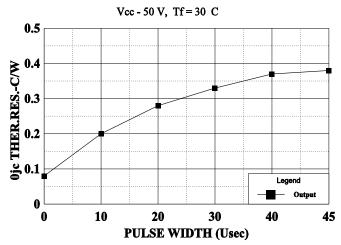
0 950

1000

Pout (WATTS)

## **DME 375A**





SERIES INPUT IMPEDANCE vs FREQUENCY

**FREQUENCY(MHz)** 

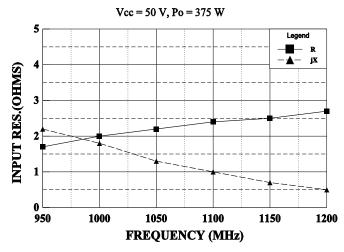
1100

1050

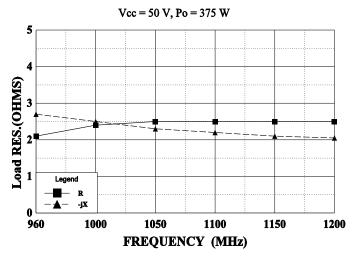
Legend — Pout

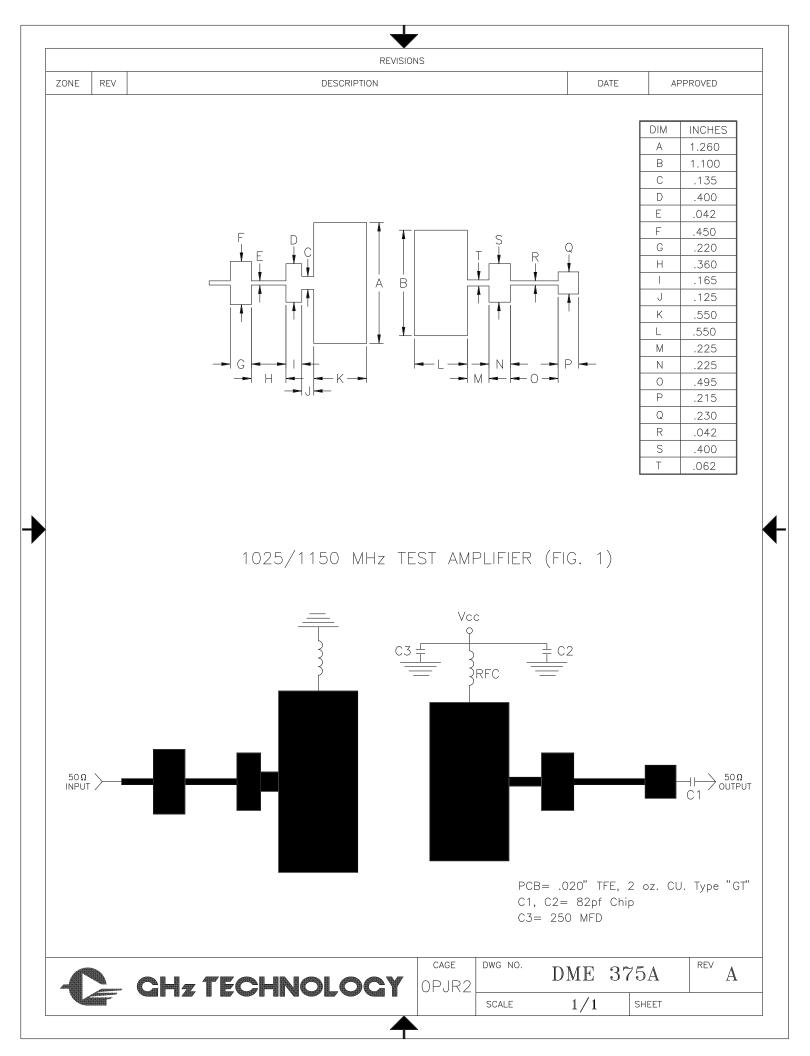
1200

1150



SERIES LOAD IMPEDANCE vs FREQUENCY





	A A V	B (			$ \begin{array}{c}                                     $
	-			— K — J	
DIM	MILLIMETER	TOL	INCHES	TOL	STYLE 1:
A	20.32	.76	.800	.050	PIN1 = COLLECTOR $2 = BASE$
В	10.16	.13	.400	.005	2 - DASE 3 = EMITTER
С	9.78	.13	.385	.005	
D	45°	5°	45°	5°	STYLE 2: PIN1 = COLLECTOR
E	3.81	.13	.150	.005	2 = EMITTER
F	1.52	.13	.060	.005	3 = BASE
G	1.52R	.13	.060R	.005	
Н	3.05	.13	.120	.005	
	3.30 DIA	.13	.130 DIA	.005	
J	22.86	.13	.900	.005	
К	16.51	.13	.650	.005	
М	4.70	REF	.185	REF	
N	0.13	.02	.005	.001	
	<u> </u>		INOLO dn power trans		dwg no. 55AW